NSN 5961-01-333-8516

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-333-8516 **Inclosure Material:** Glass **Overall Length:** Between 0.140 inches and 0.180 inches **Terminal Length:** 1.000 inches **Overall Diameter:** Between 0.075 inches and 0.080 inches **End Application:** 5865-01-188-3309 jamming system, communications, general utility Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-35 **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 35.0 reverse voltage, peak **Current Rating Per Characteristic:** 100.00 milliamperes forward current, average absolute and 300.00 milliamperes source cutoff current preset **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector absolute **Capacitance Rating In Picofarads:** 3.0 **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No

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